NPN 5A 60V Middle Power Transistor

Parameter	Value
V_{CEO}	60V
I _C	5A

Features

1) Suitable for Middle Power Driver

2) Complementary PNP Types: 2SA1952

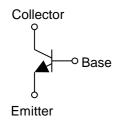
3) Low V_{CE(sat)}

 $V_{\text{CE(sat)}}\text{=}0.3V(\text{Max.})\;(I_{\text{C}}/I_{\text{B}}\text{=}3\text{A}/0.15\text{A})$

 $V_{CE(sat)} = 0.5V(Max.) (I_C/I_B = 4A/0.2A)$

4) Lead Free/RoHS Compliant.

•Inner circuit



Outline



Applications

Motor driver , LED driver Power supply

Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SC5103	CPT3	6595	TL	330	16	2,500	C5103

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	100	V
Collector-emitter voltage		V_{CEO}	60	V
Emitter-base voltage		V_{EBO}	5	V
Collector current	DC	I _C	5	А
	Pulsed	I _{CP} *1	10	А
Power dissipation		P _D *2	1	W
		P_{D}^{*3}	10	W
Junction temperature		T _j	150	°C
Range of storage temperature		T_{stg}	−55 to +150	°C

- *1 Pw=100ms, single pulse
- *2 Mounted on a substrate
- *3 Tc=25°C

●Electrical characteristics (Ta = 25°C)

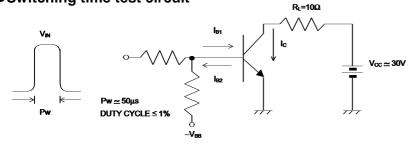
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C = 1mA	60	-	-	V
Collector-base breakdown voltage	BV _{CBO}	I _C = 50μA	100	ı	ı	V
Emitter-base breakdown voltage	BV _{EBO}	$I_E = 50\mu A$	5	ı	ı	V
Collector cut-off current	I _{CBO}	V _{CB} = 100V	-	ı	10	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 5V	-	ı	10	μΑ
Collector-emitter	*1	$I_C = 3A, I_B = 0.15A$	-	0.15	0.3	V
saturation voltage	V _{CE(sat)} 1	$I_C = 4A, I_B = 0.2A$	-	ı	0.5	V
Base-emitter saturation voltage	$V_{\rm RF(sat)}^{*1}$	$I_C = 3A, I_B = 0.15A$	-	ı	1.2	V
		$I_C = 4A, I_B = 0.2A$	-	ı	1.5	V
DC current gain	h _{FE} 1	$V_{CE} = 2V, I_C = 1A$	120	ı	270	-
	h _{FE} 2	$V_{CE} = 2V, I_C = 3A$	40	-	-	-
Transition frequency	f _T *1	$V_{CE} = 10V, I_{E} = -0.5A$ f=30MH _Z	-	120	-	MHz
Output capacitance	C _{ob}	$V_{CB} = 10V$, $I_E = 0A$ f = 1MHz	-	80	-	pF
Turn-on time	t _{on} *2	I _C =3A	-	-	0.3	ns
Storage time	t _{stg} *2	I _{B1} =0.15A I _{B2} = −0.15A	-	-	1.5	ns
Fall time	t _f *2	V _{cc} ≃30V	-	0.1	0.3	ns

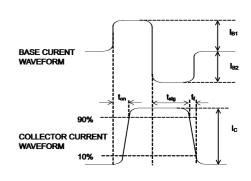
^{*1} Pulsed

●h_{FE} rank categories

Rank	Q
h _{FE}	120 to 270

•Switching time test circuit





^{*2} See switching time test circuit

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

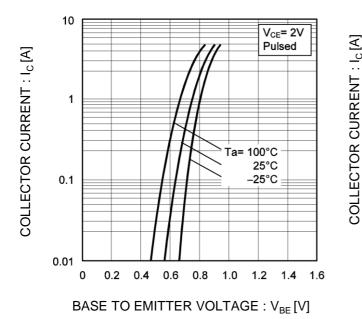
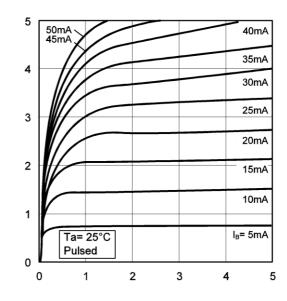


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : V_{CE}[V]

Fig.3 DC Current Gain vs. Collector Current (I)

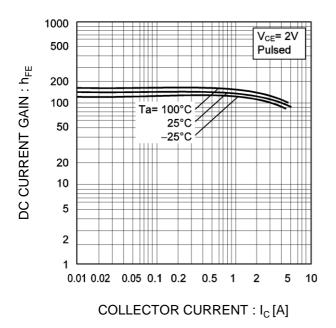
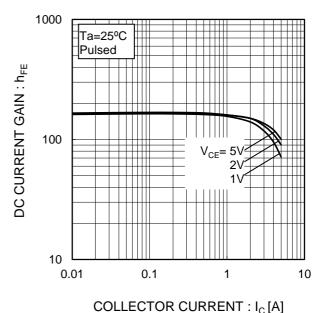


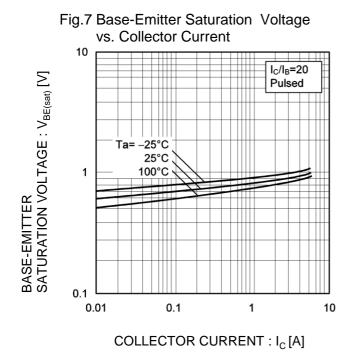
Fig.4 DC Current Gain vs. Collector Current (II)

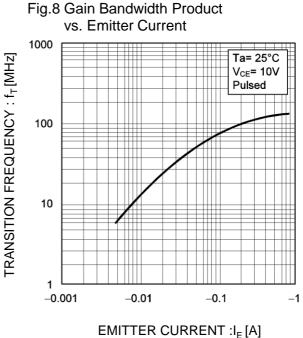


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●Electrical characteristic curves(Ta = 25°C)

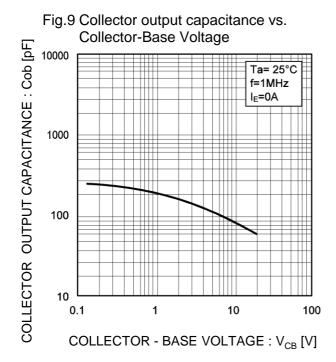
Fig.6 Collector-Emitter Saturation Voltage Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current (II) vs. Collector Current (I) Ta=25°C I_C/I_B=20 COLLECTOR-EMITTER SATURATION VOLTAGE : V_{CE(sat)} [V] COLLECTOR-EMITTER SATURATION VOLTAGE : V_{CE(sat)} [V] Pulsed Pulsed 0.1 0.1 Ta= 100°C 25°C 0.01 10/1 0.001 0.01 0.01 0.1 1 10 0.01 0.1 1 COLLECTOR CURRENT : I_C[A] COLLECTOR CURRENT: Ic [A]





100

●Electrical characteristic curves(Ta = 25°C)



Ic Max. (Pulse*) 10 Pw= 10ms* COLLECTOR CURRENT: I_C [A] Pw= 100ms* DC 1

*Single non repetitive pulse

Fig.10 Safe Operating Area

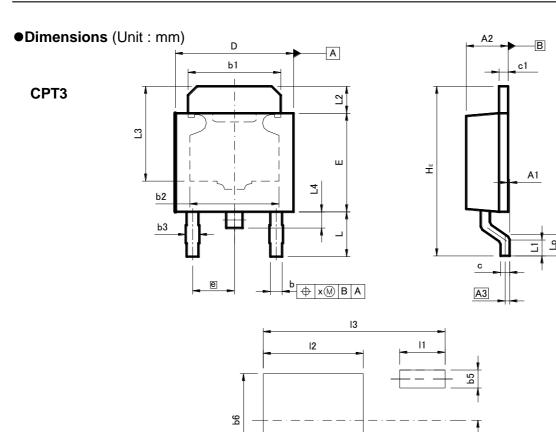
Tc= 25°C

0.1

COLLECTOR TO EMITTER VOLTAGE : $V_{CE}\left[V\right]$

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5/6



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
A1	0.00	0.15	0.000	0.006	
A2	2.20	2.50	0.087	0.098	
A3	0.:	25	0.010		
b	0.55	0.75	0.022	0.030	
b1	5.00	5.30	0.197	0.209	
b2	5.0		0.1	97	
b3	0.	75	0.0	30	
С	0.40	0.60	0.016	0.024	
с1	0.40	0.60	0.016	0.024	
D	6.30	6.70	0.248	0.264	
Е	5.40	5.80	0.213	0.228	
е	2.3	30	0.091		
HE	9.00	10.00	0.354	0.394	
L	2.20	2.80	0.087	0.110	
L1	0.80	1.40	0.031	0.055	
L2	1.20	1.80	0.047	0.071	
L3	5.30		0.209		
L4	0.90		0.035		
Lр	1.00	1.60	0.039	0.063	
X	_	0.25	_	0.010	

DIM	MILIMI	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
b5	ı	1.00	ı	0.04	
b6	1	5.20	ı	0.205	
I1	-	2.50	-	0.098	
12	_	5.50	_	0.217	
13	-	10.00	_	0.394	

Dimension in mm / inches

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